

L Number	Hits	Search Text	DB	Time stamp
-	69	polysilicon same silicon adj tetrachloride	USPAT	2004/10/20 13:04
-	20	polysilicon same silicon adj tetrachloride	US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/19 16:45
-	721	high adj k adj dielectric same gate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/19 16:46
-	592	high adj k adj dielectric with gate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/19 16:46
-	288	high adj k adj dielectric with gate	USPAT	2004/10/19 17:16
-	18	polysilicon near2 gate with (ald or pvd)	USPAT	2004/10/20 09:54
-	401	polysilicon with (ald or pvd)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/20 09:41
-	43	polysilicon with silicon adj tetrachloride	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/20 09:43
-	4	polysilicon same high adj k near1 dielectric same hydrogen near2 free	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/20 10:21